

PS9905

2.5 A OUTPUT CURRENT, HIGH CMR, IGBT GATE DRIVE, 8-PIN LSDIP PHOTOCOUPLER FOR CREEPAGE DISTANCE OF 14.5 mm

DESCRIPTION

The PS9905 is optically coupled isolator containing a GaAlAs LED on the input side and a photo diode, a signal processing circuit and a power output transistor on the output side on one chip.

FEATURES

- Long creepage distance (14.5 mm MIN.)
- Large peak output current (2.5 A MAX., 2.0 A MIN.)
- High speed switching (t_{PLH} , $t_{PHL} = 0.15 \ \mu s$ MAX.)
- UVLO (Under Voltage Lock Out) protection with hysteresis
- High common mode transient immunity (CM_H, CM_L = $\pm 25 \text{ kV}/\mu \text{s}$ MIN.)
- 8-pin LSDIP (Long Creepage SDIP) type
- Embossed tape product: PS9905-F3: 1 000 pcs/reel
- Pb-Free Product
- Safety standards

<R>

- UL approved: No. E72422
- CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
- SEMKO approved: No. 1122994
- DIN EN60747-5-5 (VDE0884-5): 2011-11 approved: No. 40034588 (Option)

APPLICATIONS

- IGBT, Power MOS FET Gate Driver
- Industrial inverter
- Solar inverter

PIN CONNECTION (Top View) 7 6 8 5 1. NC 2. Anode 3. Cathode 4. NC 5. Vee 6. NC 7. Vo 8. Vcc П 2 3 4 1

The mark <R> shows major revised points.

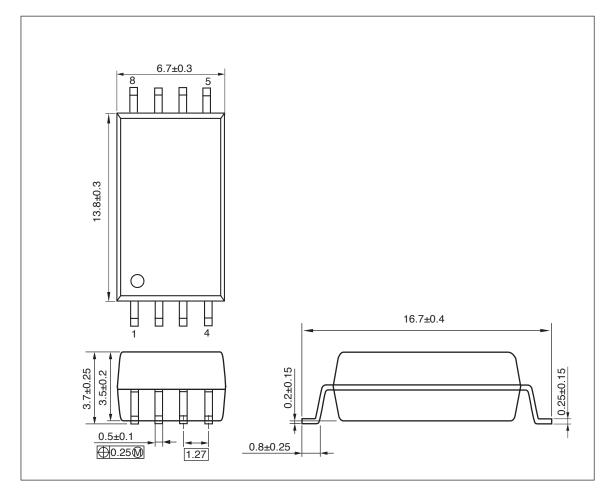
The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.



Data Sheet

R08DS0058EJ0100 Rev.1.00 Jun 11, 2012

PACKAGE DIMENSIONS (UNIT: mm)



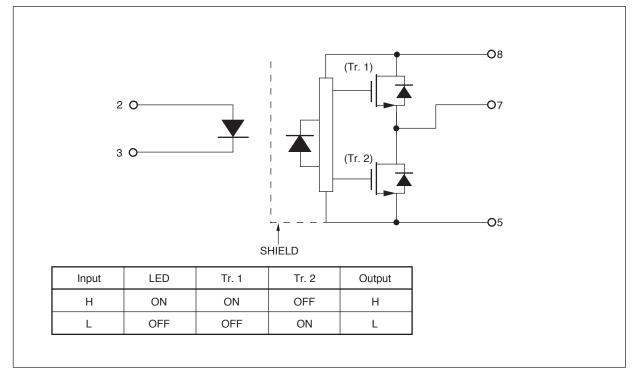
PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)
Air Distance	14.5 mm
Outer Creepage Distance	14.5 mm
Isolation Distance	0.4 mm

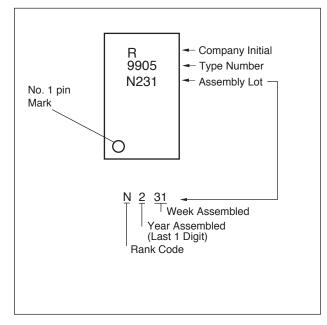




FUNCTIONAL DIAGRAM



MARKING EXAMPLE





<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{*1}
PS9905	PS9905-Y-AX	Pb-Free	10 pcs (Tape 10 pcs cut)	Standard products	PS9905
PS9905-F3	PS9905-Y-F3-AX	(Ni/Pd/Au)	Embossed Tape 1 000	(UL, CSA, SEMKO	
			pcs/reel	approved)	
PS9905-V	PS9905-Y-V-AX		10 pcs (Tape 10 pcs cut)	DIN EN60747-5-5	
PS9905-V-F3	PS9905-Y-V-F3-AX		Embossed Tape 1 000	(VDE0884-5):	
			pcs/reel	2011-11	
				approved (Option)	

Note: *1. For the application of the Safety Standard, following part number should be used.

<R> ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current	I _F	25	mA
Peak Transient Forward Current (Pulse Width < 1 μ s)		I _{F (TRAN)}	1.0	A
	Reverse Voltage	V _R	5	V
	Power Dissipation ^{*1, *6}	PD	45	mW
Detector High Level Peak Output Current ^{*2}		I _{OH (PEAK)}	2.5	A
	Low Level Peak Output Current ^{*2}	I _{OL (PEAK)}	2.5	A
	Supply Voltage	(V _{CC} - V _{EE})	0 to 35	V
	Output Voltage	Vo	0 to V _{CC}	V
	Power Dissipation ^{*3, *6}	Pc	250	mW
	Isolation Voltage *4		7 500	Vr.m.s.
Operating Frequency *5		f	50	kHz
Operating Ambient Temperature		T _A	-40 to +110	°C
Storage Te	orage Temperature		–55 to +125	°C

Notes: *1. Derating to be set after 0.8 mW/°C at $T_A = 85^{\circ}C$ or more.

*2. Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2 %

- *3. Reduced to 5.2 mW/°C at $T_A = 85^{\circ}C$ or more
- *4. AC voltage for 1 minute at $T_A = 25^{\circ}$ C, RH = 60% between input and output. Pins 1-4 shorted together, 5-8 shorted together.
- *5. $I_{OH (PEAK)} \le 2.0 \text{ A} (\le 0.3 \ \mu\text{s}), I_{OL (PEAK)} \le 2.0 \text{ A} (\le 0.3 \ \mu\text{s})$
- *6. Mounted on glass epoxy substrate of 75 mm × 115 mm × t1.5 mm

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	$(V_{CC} - V_{EE})$	15		30	V
Forward Current (ON)	I _{F (ON)}	10	12	14	mA
Forward Voltage (OFF)	V _{F (OFF)}	-2		0.8	V
Operating Ambient Temperature	T _A	-40		110	°C



ELECTRICAL CHARACTERISTICS

(V_{EE} = GND, unless otherwise specified and refer to RECOMMENDED OPERATING CONDITIONS)

Parameter		Symbol	Conditions	MIN.	TYP. ^{*1}	MAX.	Unit
Diode	Forward Voltage	VF	I _F = 10 mA, T _A = 25°C	1.3	1.56	1.8	V
	Reverse Current	I _R	V _R = 3 V, T _A = 25°C			10	μA
	Terminal Capacitance	Ct	$f = 1 \text{ MHz}, V_F = 0 \text{ V}, T_A = 25^{\circ}\text{C}$		30		pF
Detector	High Level Output Current	I _{ОН}	$V_0 = (V_{CC} - 4 V)^{*2}$	0.5	2.0		Α
			$V_0 = (V_{CC} - 15 V)^{*3}$	2.0			
	Low Level Output Current	I _{OL}	$V_0 = (V_{EE} + 2.5 V)^{*2}$	0.5	2.0		Α
			$V_{O} = (V_{EE} + 15 \text{ V})^{*3}$	2.0			
High Level Output Voltage Low Level Output Voltage		V _{OH}	$I_0 = -100 \text{ mA}^{*4}$	$V_{CC} - 3.0$	V _{CC} – 1.5		V
		V _{OL}	I _O = 100 mA		0.1	0.5	V
	High Level Supply Current		V_0 = open, I _F = 12 mA		1.4	3.0	mA
	Low Level Supply Current	I _{CCL}	V_0 = open, V_F = -2 to +0.8 V		1.3	3.0	mA
	UVLO Threshold	V_{UVLO^+}	V _O > 5 V, I _F = 12 mA	10.8	12.3	13.4	V
		$V_{\text{UVLO}_{-}}$		9.5	11.0	12.5	
	UVLO Hysteresis	UVLO_{HYS}	V _O > 5 V, I _F = 12 mA	0.4	1.3		V
Coupled	Threshold Input Current IFLH		I ₀ = 0 mA, V ₀ > 5 V		2.9	6.0	mA
	$(L \rightarrow H)$						
	Threshold Input Voltage $(H \rightarrow L)$	V _{FHL}	I ₀ = 0 mA, V ₀ < 5 V	0.8			V

Notes: *1. Typical values at $T_A = 25^{\circ}C$

- *2. Maximum pulse width = 50 μ s, Maximum duty cycle = 0.5%.
- *3. Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2%.
- *4. V_{OH} is measured with the DC load current in this testing (Maximum pulse width = 2 ms, Maximum duty cycle = 20%).



<R> SWITCHING CHARACTERISTICS

(V_{EE} = GND, unless otherwise specified and refer to RECOMMENDED OPERATING CONDITIONS)

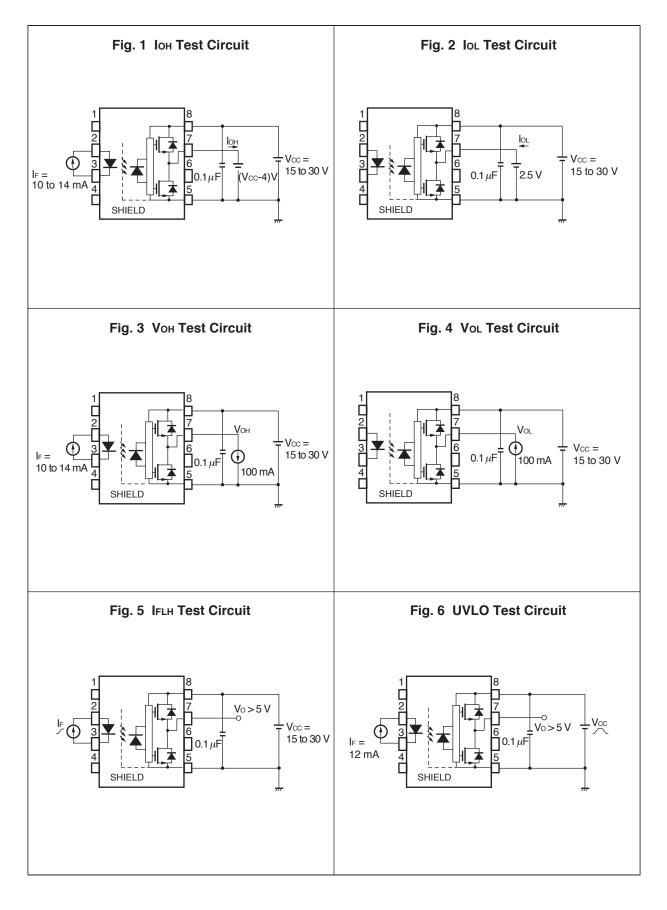
Parameter	Symbol	Conditions	MIN.	TYP. ^{*1}	MAX.	Unit
Propagation Delay Time (L \rightarrow H)	t _{PLH}	$R_g = 10 \Omega$, $C_g = 10 nF^{*2}$, f = 10 kHz,		0.09	0.15	μS
Propagation Delay Time $(H \rightarrow L)$	t _{PHL}	Duty Cycle = 50%, I_F = 12 mA		0.1	0.15	μS
Pulse Width Distortion (PWD)	t _{PHL} -t _{PLH}			0.01	0.075	μS
Propagation Delay Time (Difference Between Any Two Products)	t _{PHL} —t _{PLH}		-0.1		0.1	μs
Rise Time	tr			50		ns
Fall Time	t _f			50		ns
UVLO (Turn On Delay)	t _{UVLO ON}	V _O > 5 V, I _F = 12 mA		0.8		μS
UVLO (Turn Off Delay)	t _{UVLO OFF}	V _O < 5 V, I _F = 12 mA		0.6		μS
Common Mode Transient Immunity at High Level Output	CM _H	$ T_{A} = 25^{\circ}C, I_{F} = 12 \text{ mA}, V_{CC} = 30 \text{ V}, \\ V_{O (MIN.)} = 26 \text{ V}, V_{CM} = 1.5 \text{ kV} $	25			kV/ <i>µ</i> s
Common Mode Transient Immunity at Low Level Output	CM _L	$ \begin{array}{l} T_{A} = 25^{\circ}C, \ I_{F} = 0 \ \text{mA}, \ V_{CC} = 30 \ \text{V}, \\ V_{O \ (\text{MAX.})} = 1 \ \text{V}, \ V_{CM} = 1.5 \ \text{kV} \end{array} $	25			kV/μs

Notes: *1. Typical values at T_A = 25°C

*2. This load condition is equivalent to the IGBT load at 1 200 V / 75 A.

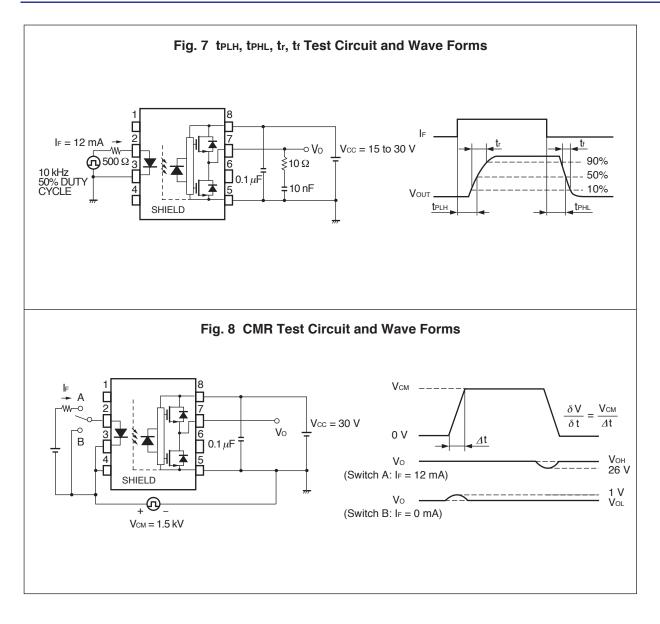


<R> TEST CIRCUIT



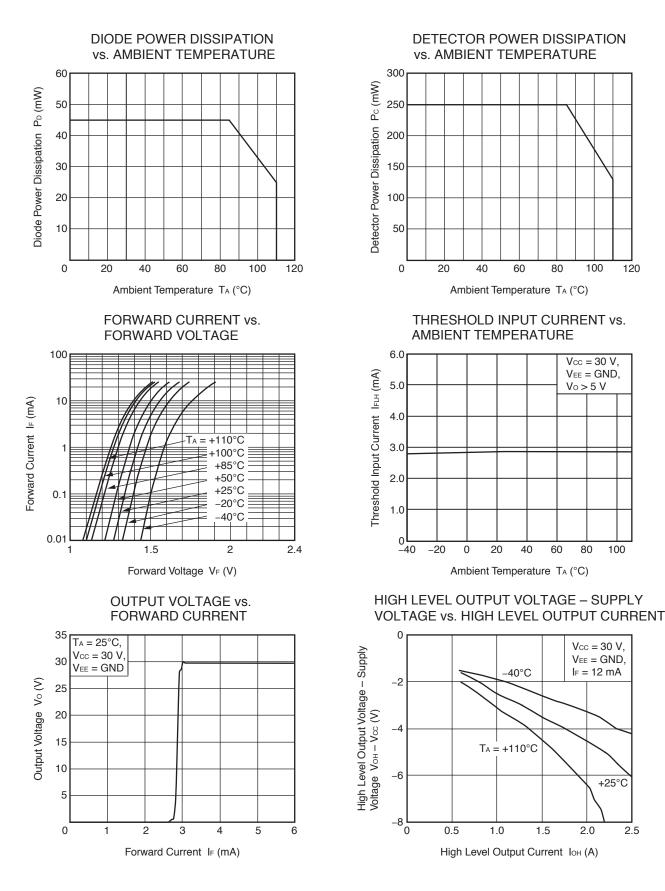


PS9905



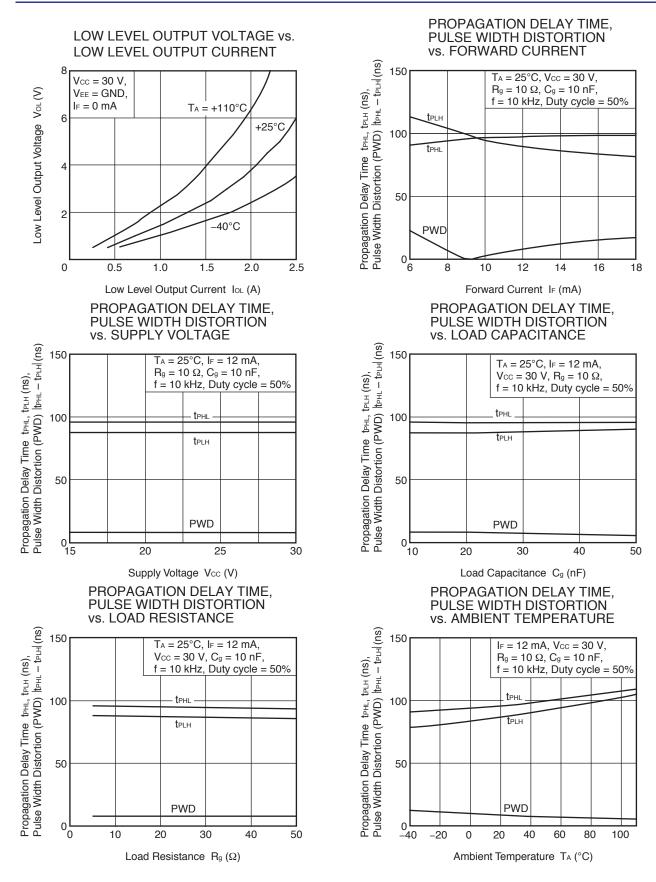


<R> TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)



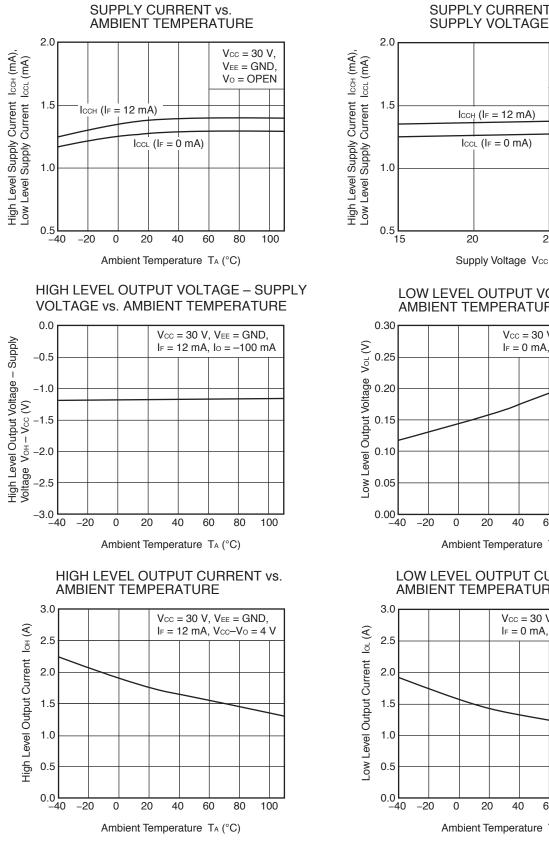
Remark The graphs indicate nominal characteristics.





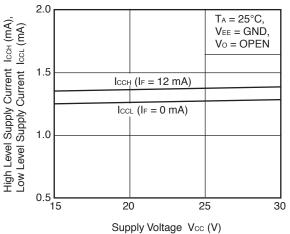
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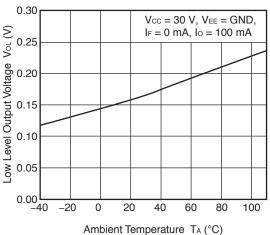


Remark The graphs indicate nominal characteristics.

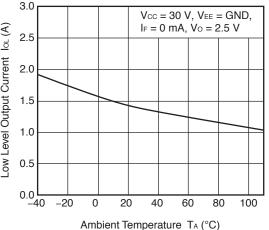
SUPPLY CURRENT vs.



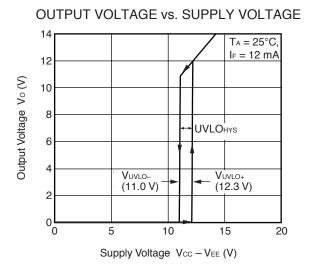
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



LOW LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



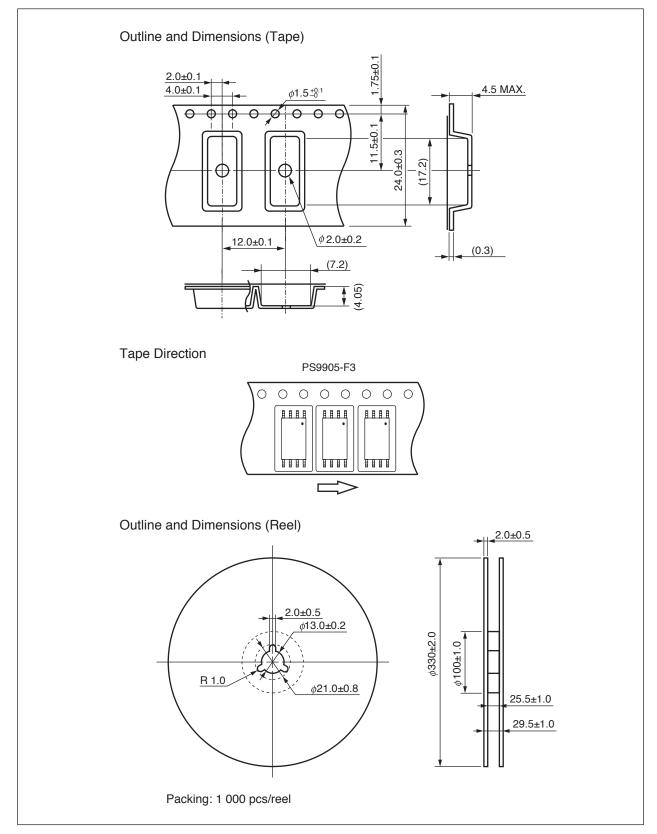
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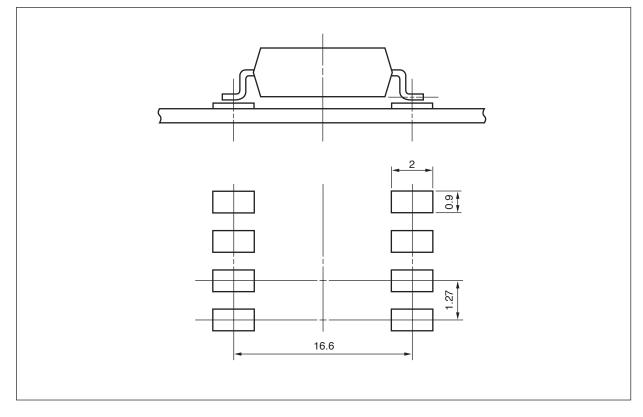
Remark The graphs indicate nominal characteristics.



TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)





NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

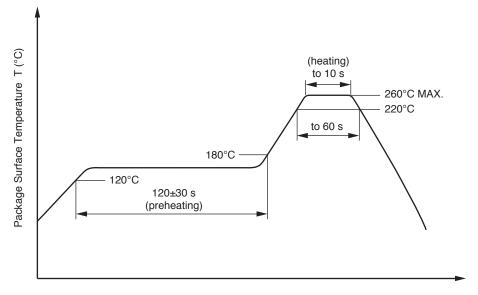
- Peak reflow temperature 260°C or below (package surface temperature)
- Time of peak reflow temperature
- Time of temperature higher than 220°C
- \bullet Time to preheat temperature from 120 to 180°C
- Number of reflows
- Flux

260°C or below (package surface temperature) 10 seconds or less

- 60 seconds or less
- 120 ± 30 s
- Three

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

• Time

• Flux

- Temperature 260°C or below (molten solder temperature)
 - 10 seconds or less
- Preheating conditions 120°C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.)
 - Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature)	350°C or below
• Time (each pins)	3 seconds or less
• Flux	Rosin flux containing small amount of chlorine (The flux with a maximum
	chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead



(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. Board designing
 - (1) By-pass capacitor of more than 0.1 μ F is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
 - (2) When designing the printed wiring board, ensure that the pattern of the IGBT collectors/emitters is not too close to the input block pattern of the photocoupler.

If the pattern is too close to the input block and coupling occurs, a sudden fluctuation in the voltage on the IGBT output side might affect the photocoupler's LED input, leading to malfunction or degradation of characteristics.

(If the pattern needs to be close to the input block, to prevent the LED from lighting during the off state due to the abovementioned coupling, design the input-side circuit so that the bias of the LED is reversed, within the range of the recommended operating conditions, and be sure to thoroughly evaluate operation.)

(3) Pin 1, 4 (which is an NC^{*1} pin) can either be connected directly to the GND pin on the LED side or left open. Also, Pin 6 (which is an NC^{*1} pin) can either be connected directly to the GND pin on the detector side or left open. Unconnected pins should not be used as a bypass for signals or for any other similar purpose because this may degrade the internal noise environment of the device.

Note: *1. NC: Non-Connection (No Connection)

- 3. Make sure the rise/fall time of the forward current is 0.5 μ s or less.
- 4. In order to avoid malfunctions, make sure the rise/fall slope of the supply voltage is $3 V/\mu s$ or less.
- 5. Avoid storage at a high temperature and high humidity.



<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/110/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	1 600	V _{peak}
Test voltage (partial discharge test, procedure a for type test and random test)	U _{pr}	2 560	V _{peak}
$U_{pr} = 1.6 \times U_{IORM.}, P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	U_{pr}	3 000	V _{peak}
$U_{pr} = 1.875 \times U_{IORM.}, P_{d} < 5 pC$			
Highest permissible overvoltage	U _{TR}	12 000	V _{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	T _{stg}	-55 to +125	°C
Operating temperature range	T _A	-40 to +110	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc at } T_A = 25^{\circ}\text{C}$	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current I _F , Psi = 0)	lsi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance		0	
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω





Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	 Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	 Do not lick the product or in any way allow it to enter the mouth.



Revision History

PS9905 Data Sheet

		Description		
Rev.	Date	Page	Summary	
0.01	Apr 06, 2012	-	First edition issued	
1.00	Jun 11, 2012	Throughout	Preliminary Data Sheet \rightarrow Data Sheet	
		p.1	Modification of FEATURES	
		p.4	Modification of ORDERING INFORMATION	
		p.5	Modification of ABSOLUTE MAXIMUM RATINGS	
		p.6	Modification of SWITCHING CHARACTERISTICS	
		pp.7, 8	Modification of TEST CIRCUIT	
		pp.9 to 12	Addition of TYPICAL CHARACTERISTICS	
		p.17	Addition of SPECIFICATION OF VDE MARKS LICENSE DOCUMENT	

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